

**PCT REQUEST**

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0	<b>For receiving Office use only</b>	
0-1	International Application No.	
0-2	International Filing Date	
0-3	Name of receiving Office and "PCT International Application"	
0-4	<b>Form PCT/RO/101 PCT Request</b>	
0-4-1	Prepared Using	<b>PCT-SAFE [EASY mode] Version 3.50 (Build 0002.170)</b>
0-5	<b>Petition</b>  The undersigned requests that the present international application be processed according to the Patent Cooperation Treaty	
0-6	Receiving Office (specified by the applicant)	<b>Japan Patent Office (RO/JP)</b>
0-7	Applicant's or agent's file reference	<b>FP03-0399-00</b>
I	Title of Invention	<b>PHOTOELECTRIC TRANSDUCER, PHOTOELECTRIC TRANSDUCER APPARATUS, AND IRON SILICIDE FILM</b>
II	<b>Applicant</b>	
II-1	This person is	<b>applicant only</b>
II-2	Applicant for	<b>all designated States except US</b>
II-4	Name	<b>TDK Corporation</b>
II-5	Address	<b>1-13-1, Nihonbashi, Chuo-ku, Tokyo 1038272</b>
II-6	State of nationality	<b>Japan</b>
II-7	State of residence	<b>JP</b>
III-1	<b>Applicant and/or Inventor</b>	
III-1-1	This person is	<b>applicant only</b>
III-1-2	Applicant for	<b>all designated States except US</b>
III-1-4	Name	<b>SEMICONDUCTOR ENERGY LABORATORY CO., LTD.</b>
III-1-5	Address	<b>398, Hase Atsugi-shi, Kanagawa 2430036</b>
III-1-6	State of nationality	<b>Japan</b>
III-1-7	State of residence	<b>JP</b>

**PCT REQUEST**

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<b>III-2</b>	<b>Applicant and/or Inventor</b>	
III-2-1	This person is	<b>applicant and inventor</b>
III-2-2	Applicant for	<b>US only</b>
III-2-4	Name (LAST, First)	<b>YAMADA, Hiroshi</b>
III-2-5	Address	(c/o) TDK Corporation 1-13-1, Nihonbashi, Chuo-ku, Tokyo 1038272 <b>Japan</b>
III-2-6	State of nationality	<b>JP</b>
III-2-7	State of residence	<b>JP</b>
<b>III-3</b>	<b>Applicant and/or Inventor</b>	
III-3-1	This person is	<b>applicant and inventor</b>
III-3-2	Applicant for	<b>US only</b>
III-3-4	Name (LAST, First)	<b>MOROOKA, Hisao</b>
III-3-5	Address	(c/o) TDK Corporation 1-13-1, Nihonbashi, Chuo-ku, Tokyo 1038272 <b>Japan</b>
III-3-6	State of nationality	<b>JP</b>
III-3-7	State of residence	<b>JP</b>
<b>III-4</b>	<b>Applicant and/or Inventor</b>	
III-4-1	This person is	<b>applicant and inventor</b>
III-4-2	Applicant for	<b>US only</b>
III-4-4	Name (LAST, First)	<b>NISHI, Kazuo</b>
III-4-5	Address	c/o SEMICONDUCTOR ENERGY LABORATORY CO., LTD., 398, Hase Atsugi-shi, Kanagawa 2430036 <b>Japan</b>
III-4-6	State of nationality	<b>JP</b>
III-4-7	State of residence	<b>JP</b>

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<b>IV-1</b>	<b>Agent or common representative; or address for correspondence</b> The person identified below is hereby/ has been appointed to act on behalf of the applicant(s) before the competent International Authorities as:	<b>agent</b>
IV-1-1	Name (LAST, First)	<b>HASEGAWA, Yoshiki</b>
IV-1-2	Address	<b>SOEI PATENT AND LAW FIRM, Ginza First Bldg., 10-6, Ginza 1-chome Chuo-ku, Tokyo 1040061</b>
IV-1-3	Telephone No.	<b>03-3564-8001</b>
IV-1-4	Facsimile No.	<b>03-3564-8004</b>
<b>IV-2</b>	<b>Additional agent(s)</b>	<b>additional agent(s) with same address as first named agent</b>
IV-2-1	Name(s)	<b>SHIODA, Tatsuya; TERASAKI, Shiro</b>
<b>V</b>	<b>DESIGNATIONS</b>	
V-1	The filing of this request constitutes under Rule 4.9(a), the designation of all Contracting States bound by the PCT on the international filing date, for the grant of every kind of protection available and, where applicable, for the grant of both regional and national patents.	
VI-1	<b>Priority claim of earlier national application</b>	
VI-1-1	Filing date	<b>16 January 2003 (16.01.2003)</b>
VI-1-2	Number	<b>2003-008717</b>
VI-1-3	Country	<b>JP</b>
VI-2	<b>Priority document request</b> The receiving Office is requested to prepare and transmit to the International Bureau a certified copy of the earlier application(s) identified above as item(s):	<b>VI-1</b>
VII-1	<b>International Searching Authority Chosen</b>	<b>Japan Patent Office (ISA/JP)</b>

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VIII	<b>Declarations</b>	Number of declarations	
VIII-1	Declaration as to the identity of the inventor	-	
VIII-2	Declaration as to the applicant's entitlement, as at the international filing date, to apply for and be granted a patent	-	
VIII-3	Declaration as to the applicant's entitlement, as at the international filing date, to claim the priority of the earlier application	-	
VIII-4	Declaration of inventorship (only for the purposes of the designation of the United States of America)	-	
VIII-5	Declaration as to non-prejudicial disclosures or exceptions to lack of novelty	-	
<b>IX</b>	<b>Check list</b>	number of sheets	electronic file(s) attached
IX-1	Request (including declaration sheets)	<b>5</b>	✓
IX-2	Description	<b>17</b>	-
IX-3	Claims	<b>2</b>	-
IX-4	Abstract	<b>1</b>	✓
IX-5	Drawings	<b>5</b>	-
IX-7	<b>TOTAL</b>	<b>30</b>	
<b>Accompanying Items</b>		paper document(s) attached	electronic file(s) attached
IX-8	Fee calculation sheet	✓	-
IX-17	PCT-SAFE physical media	-	✓
IX-19	Figure of the drawings which should accompany the abstract	<b>1</b>	
IX-20	Language of filing of the international application	<b>Japanese</b>	
X-1	Signature of applicant, agent or common representative		
X-1-1	Name (LAST, First)		
X-1-2	Name of signatory		
X-1-3	Capacity		

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10-1	Date of actual receipt of the purported International application	
10-2	Drawings: 10-2-1 Received 10-2-2 Not received	
10-3	Corrected date of actual receipt due to later but timely received papers or drawings completing the purported International application	
10-4	Date of timely receipt of the required corrections under PCT Article 11(2)	
10-5	International Searching Authority	ISA / JP
10-6	Transmittal of search copy delayed until search fee is paid	

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11-1	Date of receipt of the record copy by the International Bureau	
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